

51106



PART - B

(5×16=80 Marks)

11. a) i) Define : Relaxation time and Mean free path. (4)
- ii) Write the postulates of Lorentz and Drude theory and deduce an expression for electrical conductivity of conducting materials. (12)
- (OR)
- b) Derive a general expression for the Fermi energy of electrons in solids at 0K and show that at the same temperature, the average energy of the electron is $(3/5)^{\text{th}}$ of the Fermi energy. (16)
12. a) Derive an expression for the density of the holes in a p-type semiconductor and explain its Fermi energy varies with the temperature using diagram. (16)
- (OR)
- b) Define Hall Effect. Describe the theory of Hall Effect and how will you determine the Hall Coefficient of a semiconductor experimentally. (16)
13. a) Discuss the classification of different type of magnetic materials. (16)
- (OR)
- b) i) Distinguish between type I and type II superconductors. (8)
- ii) Write short notes on Cooper pairs and Cryotron switches. (8)
14. a) Derive an expression for Lorentz internal field and hence arrive Clausius-Mosotti equation. (16)
- (OR)
- b) i) Explain the effect of frequency dependence and temperature on different polarizations. (8)
- ii) Write short notes on Ferroelectric materials and its applications. (8)
15. a) What are metallic glasses ? Explain the rapid quenching method for the preparation of metallic glasses and write its properties. (16)
- (OR)
- b) i) Explain the pulsed laser deposition method to produce Nano materials. (8)
- ii) Write notes on Non-linear Optics. (8)